

Spectral simulations of a H-C-O-Si plasma

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For the Plasma Dynamics Laboratory, University of Washington

We present here some simple, preliminary spectral simulations using the *PrismSPECT* non-LTE modeling code (see <http://www.prismcs.com/Software/PrismSpect/PrismSPECT.htm>) and the *ATBASE ab initio* atomic models (see <http://www.prismcs.com/Software/AtomicData/AtomicData.htm>)

The assumptions for these calculations are:

Time-independent, non-LTE (“collisional radiative equilibrium”) ionization and level population calculation, with optically thin radiation transport

Predominantly hydrogen plasma, but with the following impurities, % atomic:

C: 0.25%

O: 0.50%

Si: 0.10%

$$n_{\text{ion}} = 3 \times 10^{15} \text{ cm}^{-3}$$

$$T_e = T_i = 15, 50 \text{ eV} \text{ (two separate calculations)}$$

Atomic Model

ATBASE v. 5.1

Detailed Configuration Accounting (L-S coupling):

H: 12 levels

C: 641 levels

O: 1304 levels

Si: 1678 levels

For C, O, and Si, we use all non-autoionizing levels of each ion stage (for Si, only up through Si^{+7} , above which we use only ground states)

The following five slides show the *PrismSPECT* GUI for setting up the calculations.

PrismSPECT: F:/david/Gota/run1.psi

File Edit View Simulation Display Help

Setup:

Plasma Elements

Simulation Type

Plasma Properties

Atomic Processes

Spectral Grid

Output

Run Simulation

View Results:

Spectra

Ionization

Line Intensities

At. # Element # fraction Atomic Model

1	H	0.9915	F:/david/Gota/H_12levs.atm
6	C	0.0025	F:/david/Gota/C_641levs.atm
8	O	0.005	F:/david/Gota/O_1304levs.atm
14	Si	0.001	F:/david/Gota/Si_1678levs.atm

Add... Delete

Number fractions will be normalized to 1.

Element Properties

Element: H (Z = 1) Modify... Name: Hydrogen

Number Fraction: 0.9915 At. Weight: 1.00797

Atomic Model

Model type:

Detailed configuration accounting (DCA) Tabular Data

Default

Model: Emission K-Shell Spectroscopy View...

Custom

File: F:/david/Gota/H_12levs.atm Browse... Edit...

Help Next >

PrismSPECT: F:/david/Gota/run1.psi

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Run Simulation

Atomic Rate Equations Solution

Steady-state

Time-dependent

Plasma Variables

Geometry: Zero Width Planar Spherical

Electron Distribution: Maxwellian (1-T)

Density: Mass density Ion density

Size: ΔL ρ ΔL Mass

View Results:

Spectra

Ionization

Line Intensities

External Radiation Source

External Rad. Source: None 1-T 2-T

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PrismSPECT: F:/david/Gota/run1.psi

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Setup:

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Plasma Properties

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Run Simulation

View Results:

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Ionization

Line Intensities

Steady-state Independent Variables

Independent Variable #1: None

Independent Variable #2: None

Plasma Parameters

Plasma Temperature: 15 Table... eV

Ion Density: 3e+15 Table... ions/cm³

Number Fraction: Table...

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View Results:

Spectra

Ionization

Line Intensities

Atomic Level Populations Model

Non-LTE

LTE

<< Advanced

Rate Multipliers

Photoabsorption grid

Transitions

Rate Coefficient Multipliers

Multiplier

Collisional Excitation/Deexcitation:

1

Spontaneous emission:

1

Photoexcitation/Stimulated Emission:

1

Radiative Recombination:

1

Collisional Ionization/Recombination:

1

Autoionization/Dielectronic Recombination:

1

Photoionization/Stimulated Recombination:

1

Reset to defaults

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PrismSPECT: F:/david/Gota/run1.psi

File Edit View Simulation Display Help



Setup:

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Spectral Grid

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Run Simulation

Spectral Grid

Min. Photon Energy (eV): 1.8

Points in Continuum: 1000

Max. Photon Energy (eV): 100

Additional Photon Energy Points

Number per Line Transition:

9

per Photoionization Edge: 2

Add for lines with osc. strength above: 1e-06

Increasing the number of photon energies
requires additional computation time.

Backlighter Type

None

Planckian

Temperature (eV): 1000

View Results:

Spectra

Ionization

Line Intensities

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Low temperature (15 eV) results

Ionization balance – mean charge states:

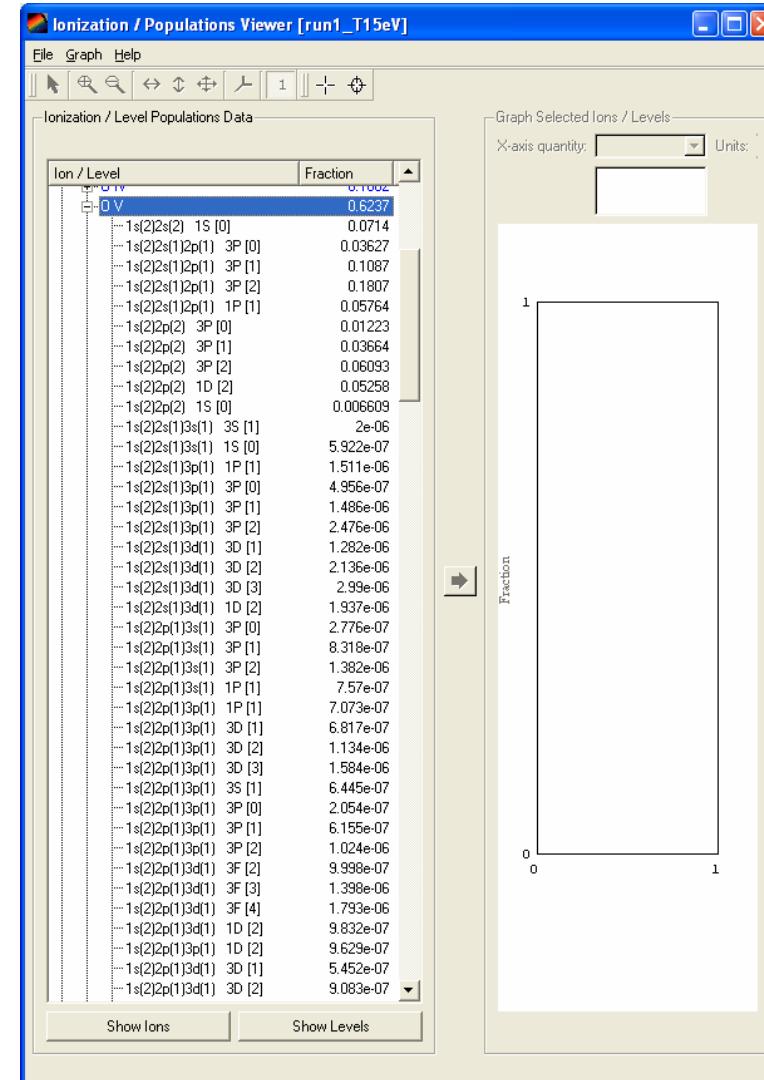
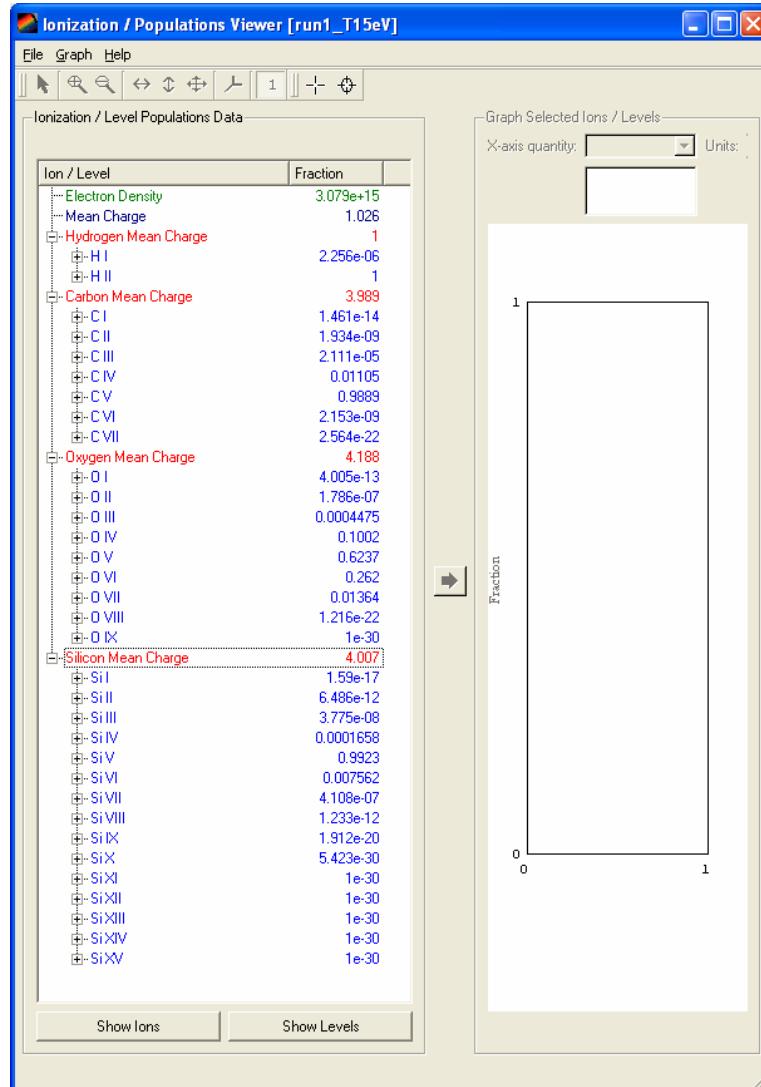
$Z_{\text{H}}: 1 (2.3 \times 10^{-6} \text{ H}^0)$

$Z_{\text{C}}: 3.99 (\sim 1\% \text{ C}^{+3})$

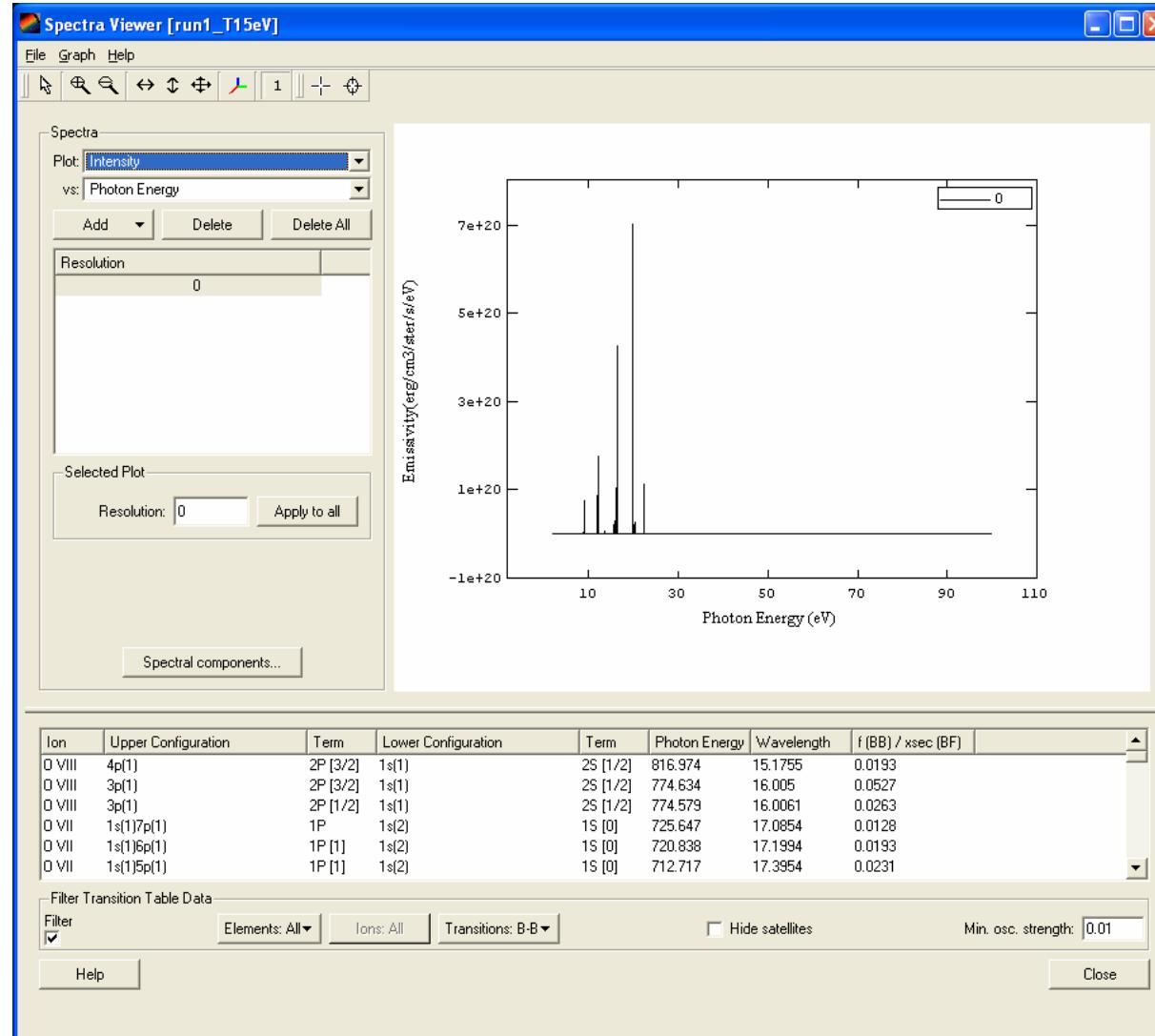
$Z_{\text{O}}: 4.19 (62\% \text{ O}^{+4}, 26\% \text{ O}^{+5}, 10\% \text{ O}^{+3},$
 $1\% \text{ O}^{+6})$

$Z_{\text{Si}}: 4.01 (>99\% \text{ Si}^{+4})$

PrismSPECT ionization and excitation output

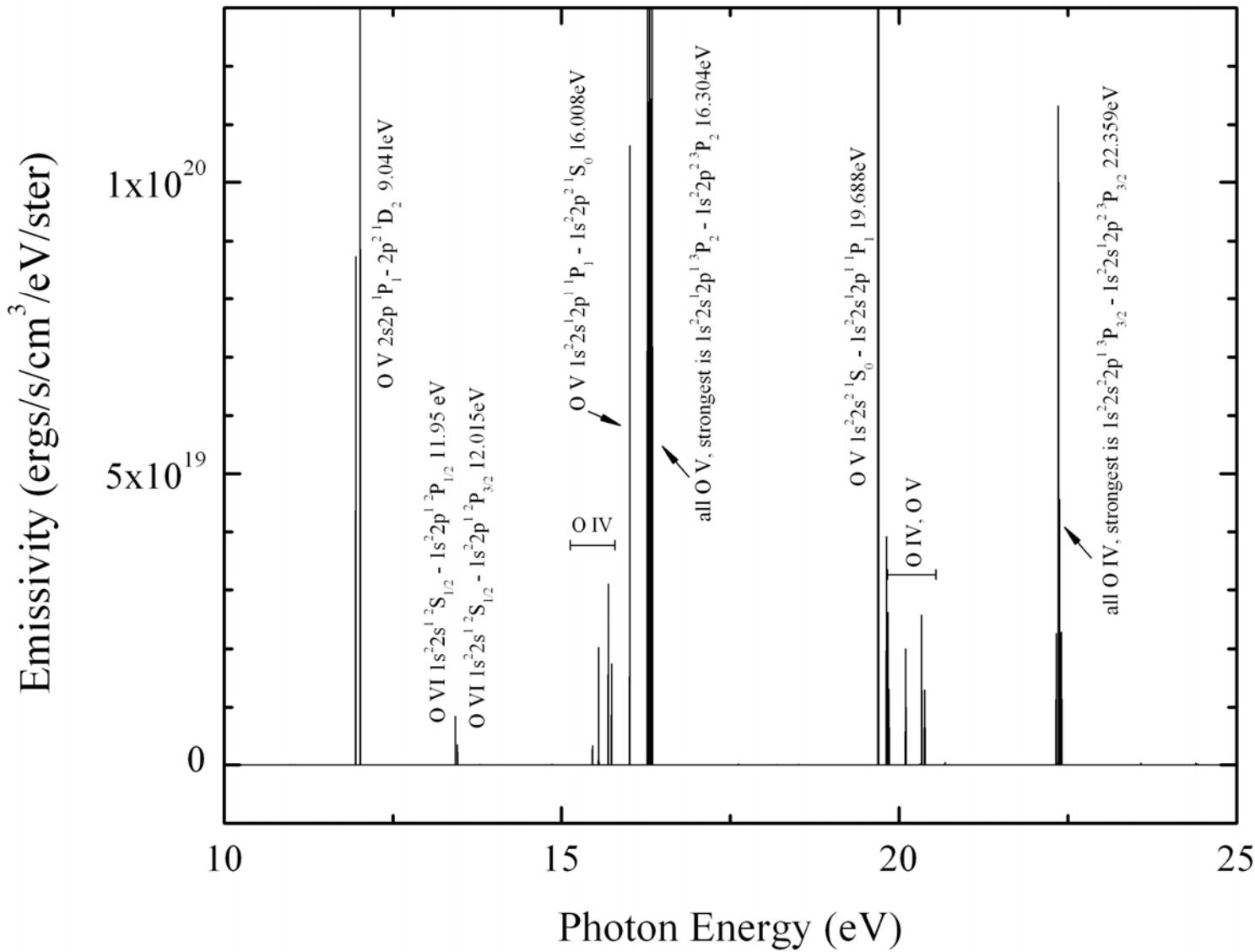


The GUI for the *PrismSPECT* spectrum viewer

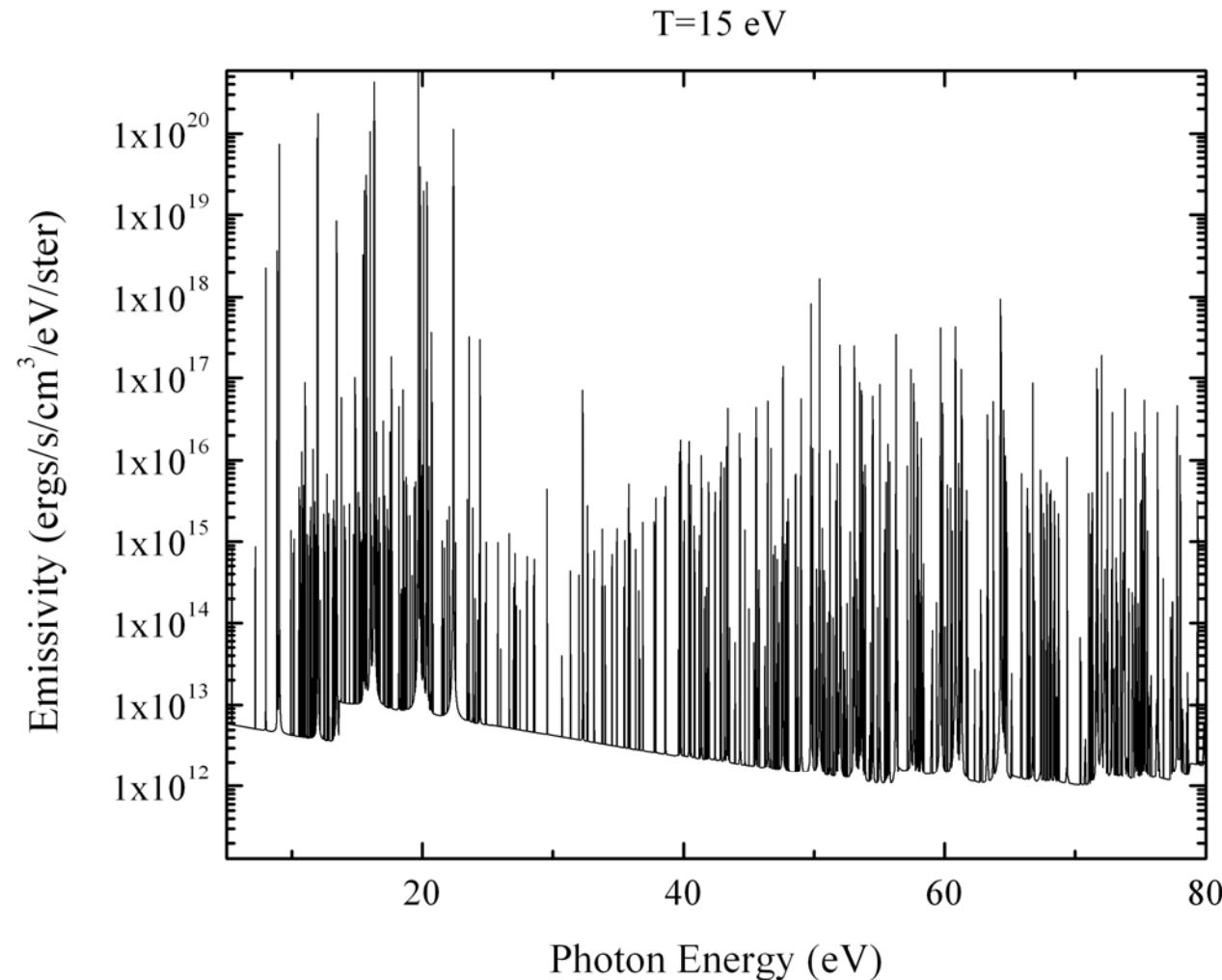


PrismSPECT simulated spectrum, with strong lines labeled...note:
every line is from oxygen

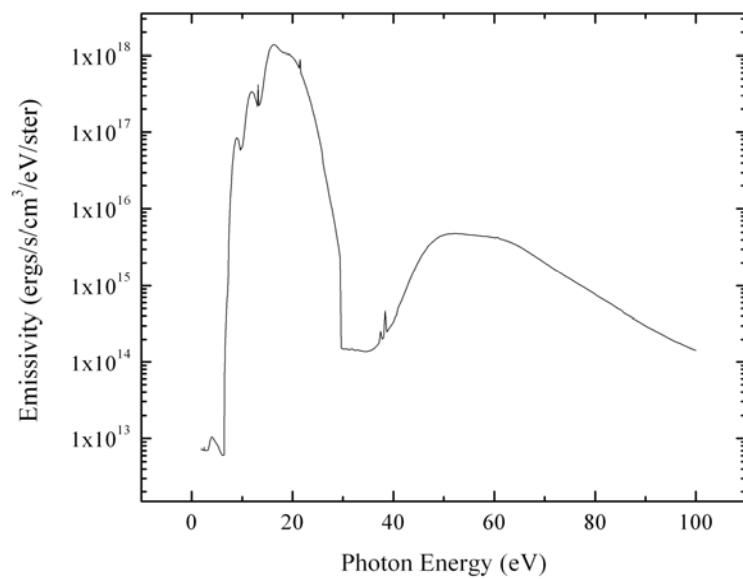
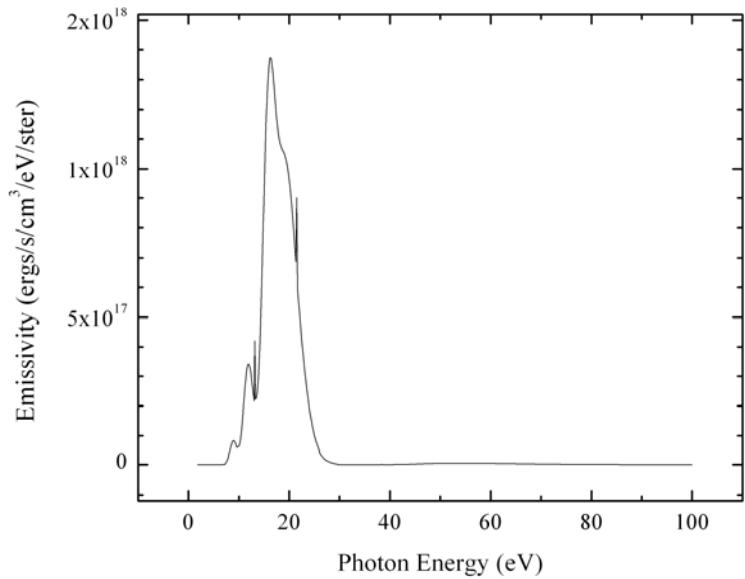
T=15 eV



Same simulated spectrum as previous slide, but with a logarithmic y-axis:
note domination of lines over continuum, and also note that the continuum is
dominated by recombination, rather than free-free emission.



Again, the same simulated spectrum, but here it is degraded down to a very low resolution. This should enable us to better estimate what signal would be expected in a broad-band EUV/soft-x-ray detector.



The only difference between these two figures are the y-axes – linear (left) vs. log (right).

We next did a second calculation,
identical in every way, except that
the plasma temperature was
increased to 50eV.

High temperature (50 eV) results

Ionization balance – mean charge states:

$Z_{\text{H}}: 1 (3.3 \times 10^{-7} \text{ H}^0)$

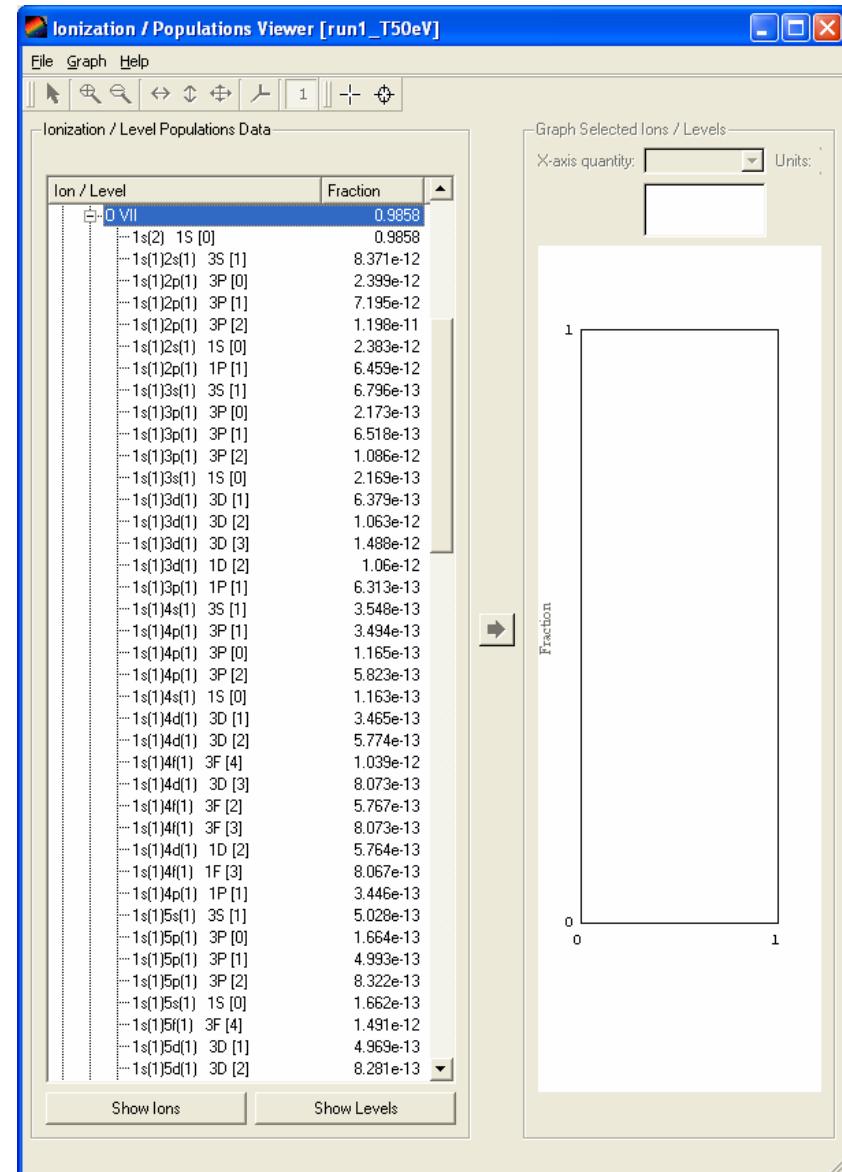
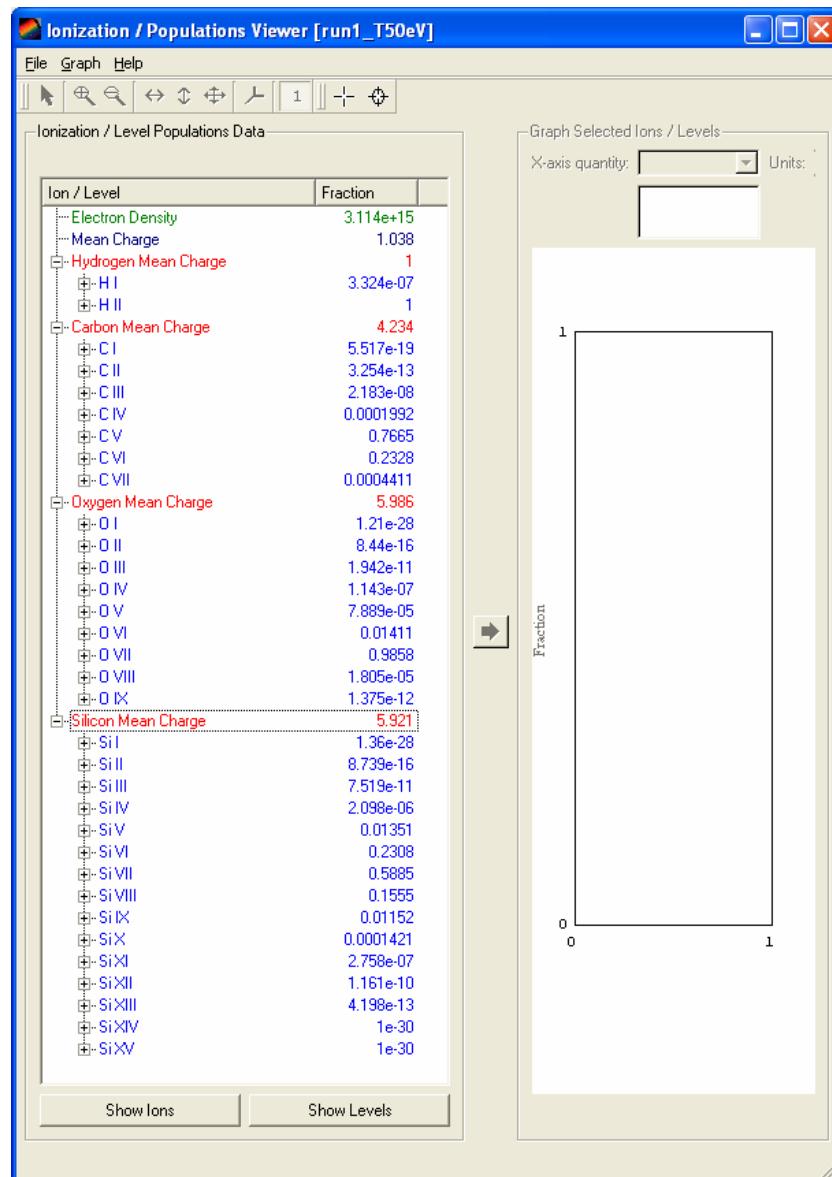
$Z_{\text{C}}: 4.23 (77\% \text{ C}^{+4}, 23\% \text{ C}^{+5})$

$Z_{\text{O}}: 5.99 (1\% \text{ O}^{+5}, 99\% \text{ O}^{+6})$

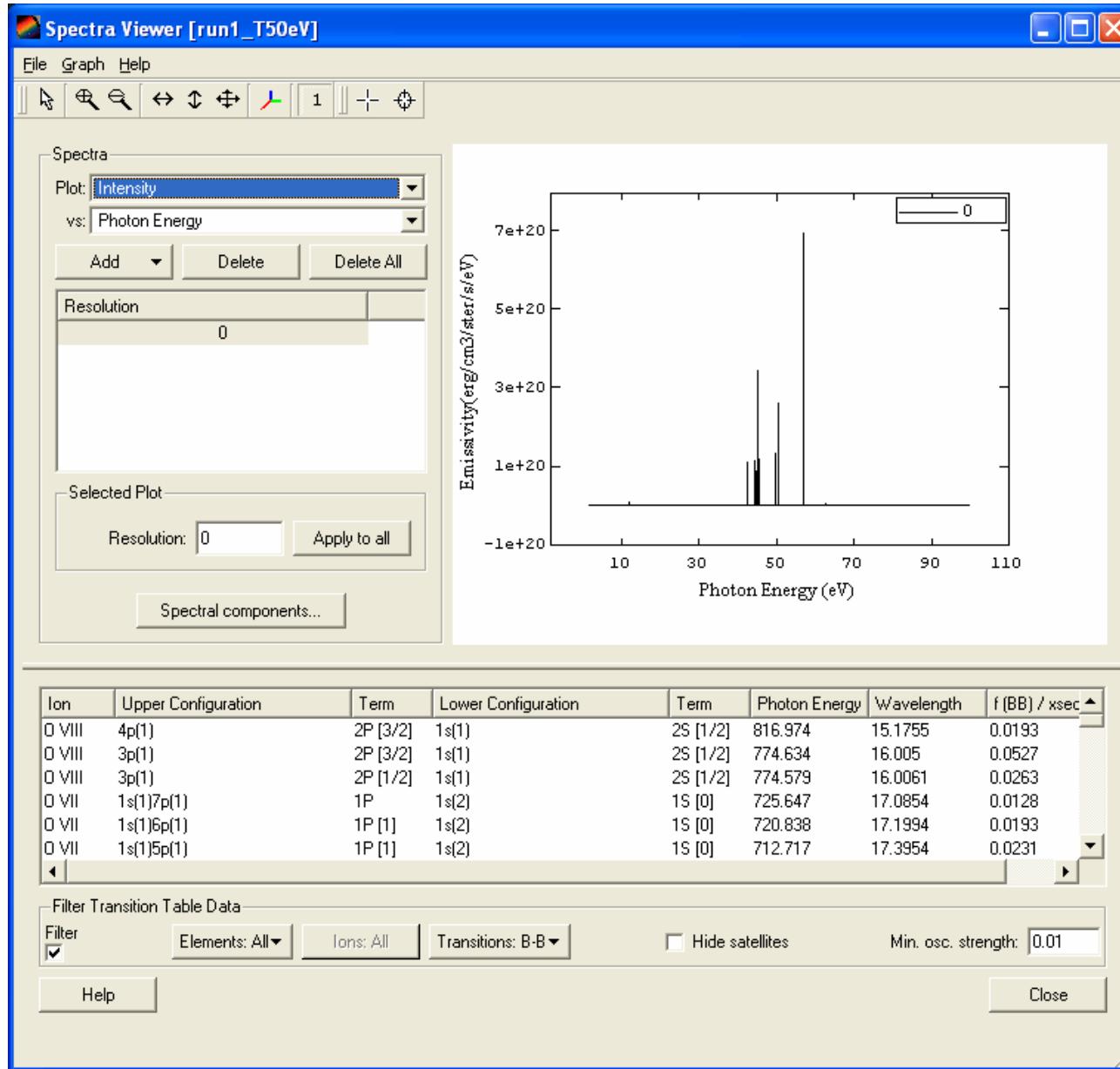
$Z_{\text{Si}}: 5.92 (1\% \text{ Si}^{+4}, 23\% \text{ Si}^{+5}, 59\% \text{ Si}^{+6}, 16\% \text{ Si}^{+7})$

Note: increase by >1 charge state,
compared to 15 eV calculation

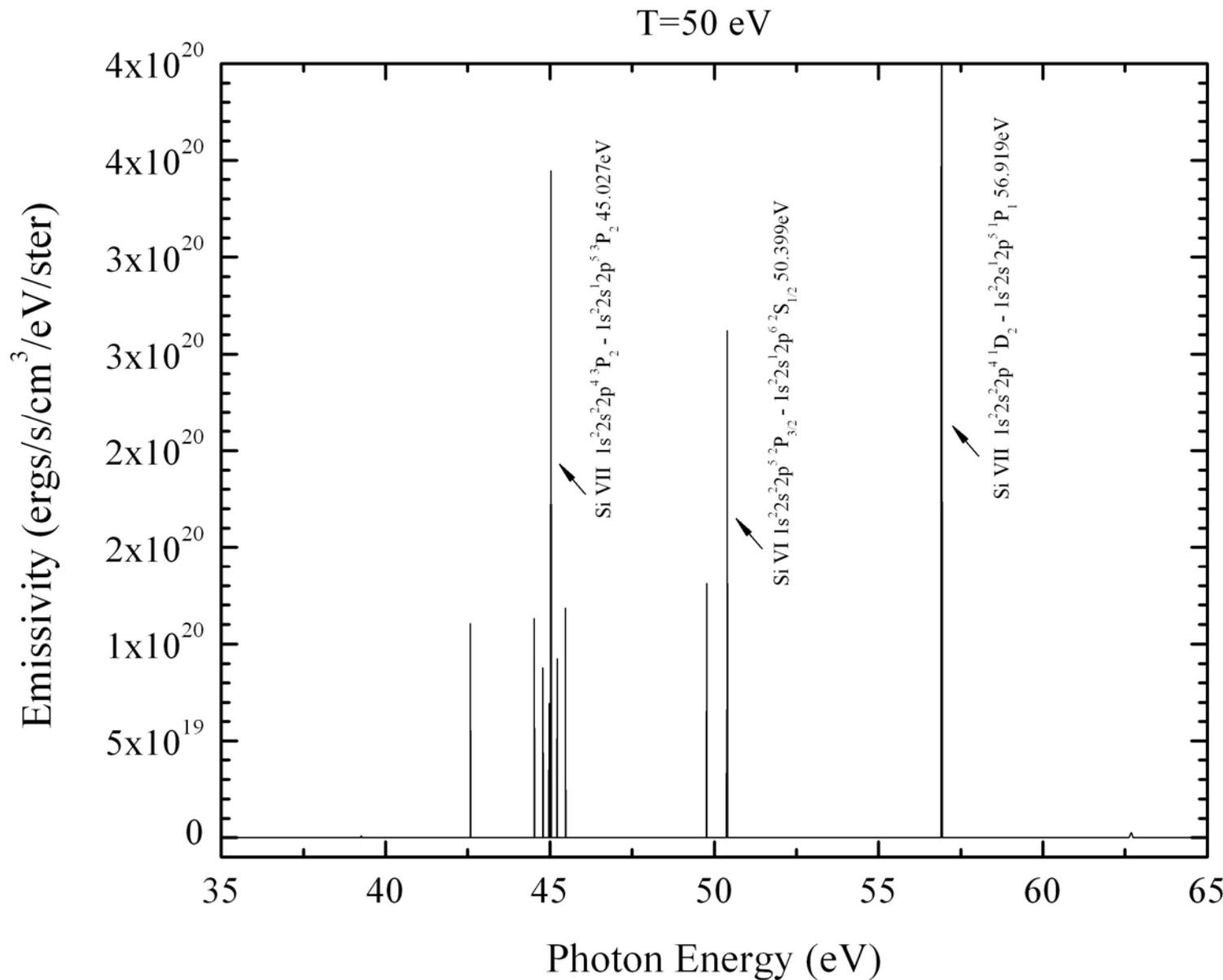
PrismSPECT ionization and excitation output



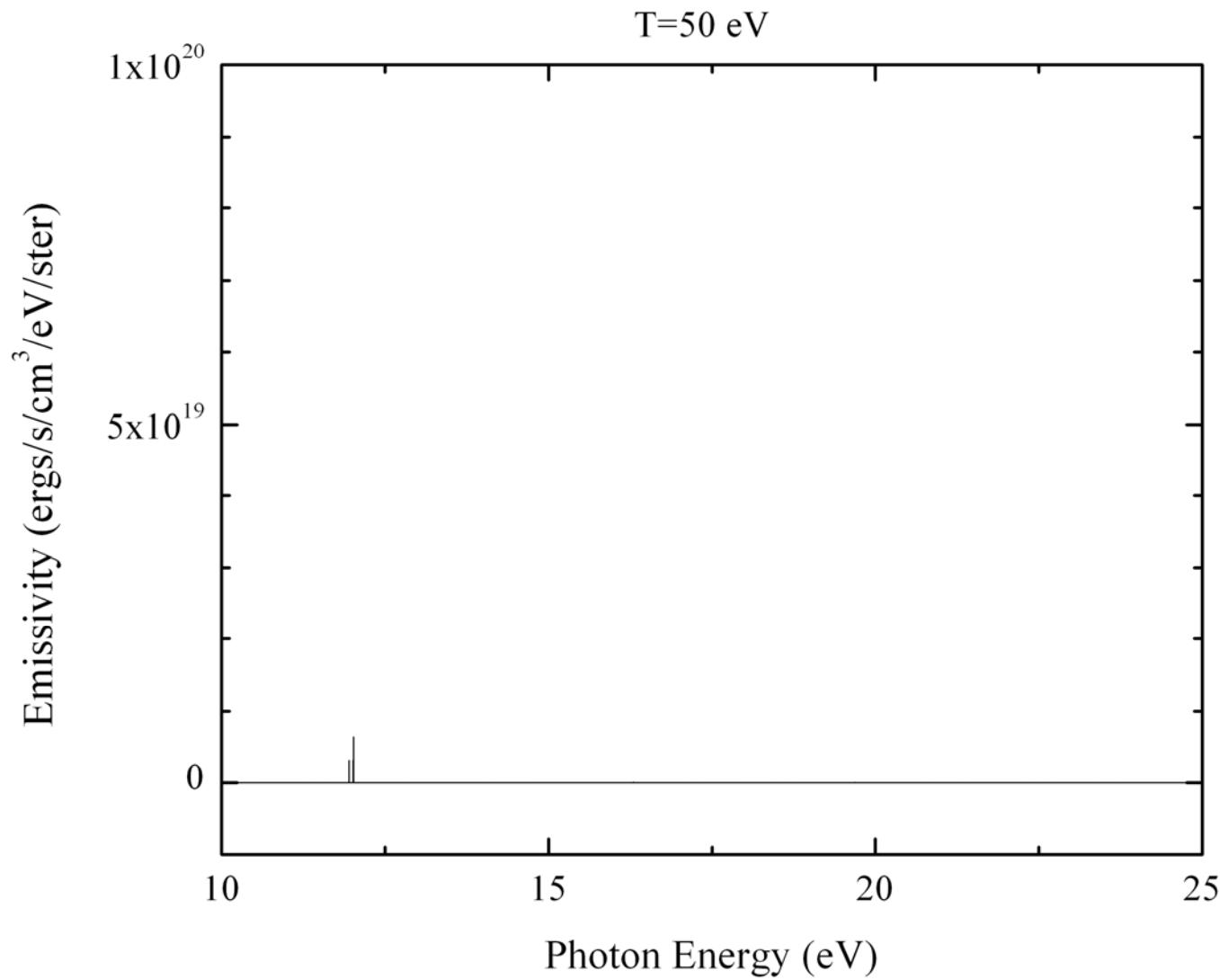
The GUI for the *PrismSPECT* spectrum viewer



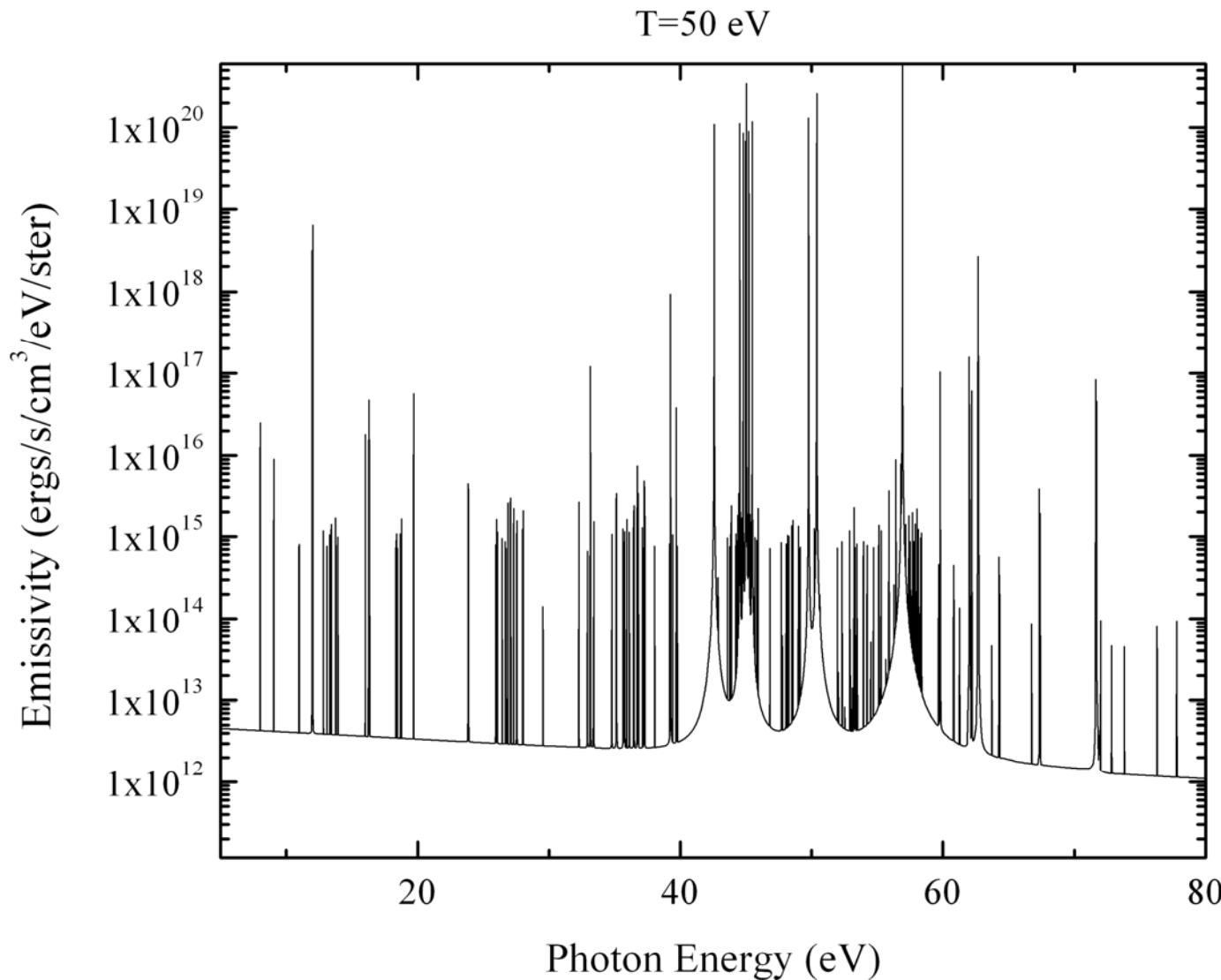
PrismSPECT simulated spectrum. Note the different wavelength coverage. Also, only the three strongest lines are identified (and they are all from silicon).



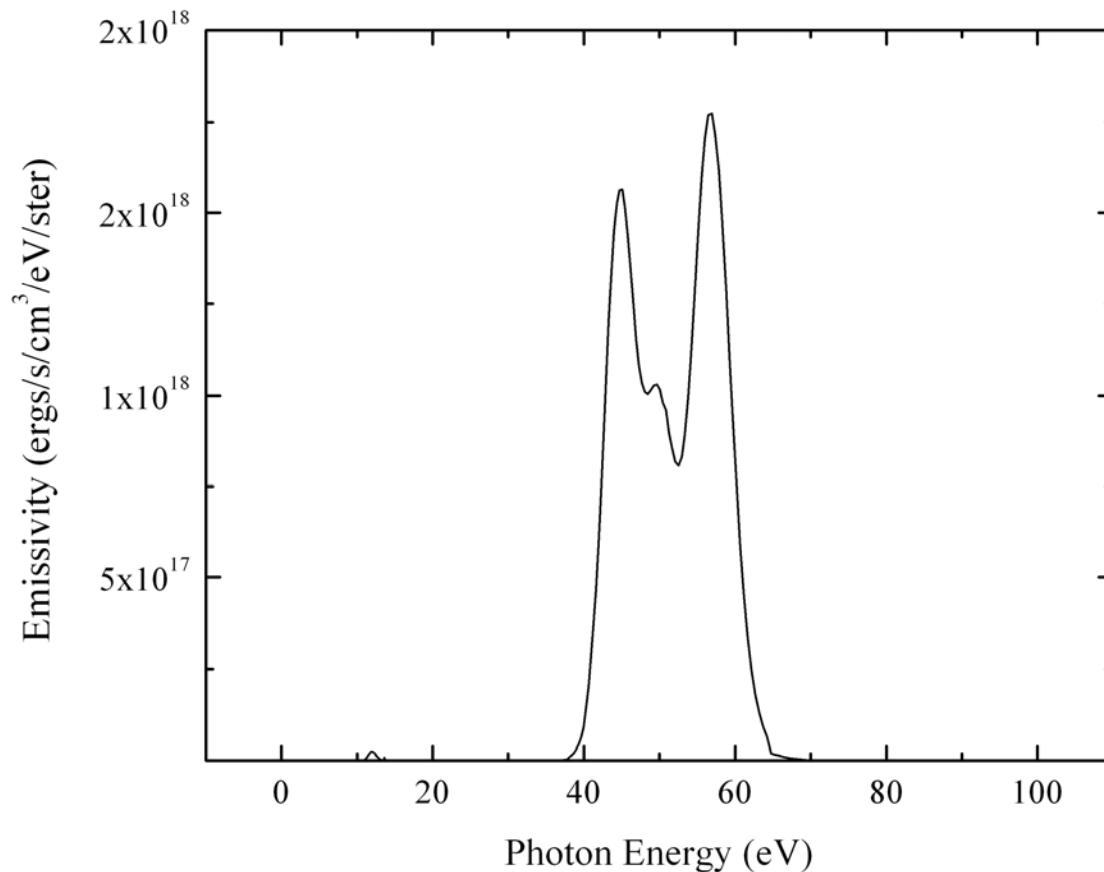
This is what the 50 eV spectrum looks like in the same photon energy range we showed for the 15 eV spectrum.



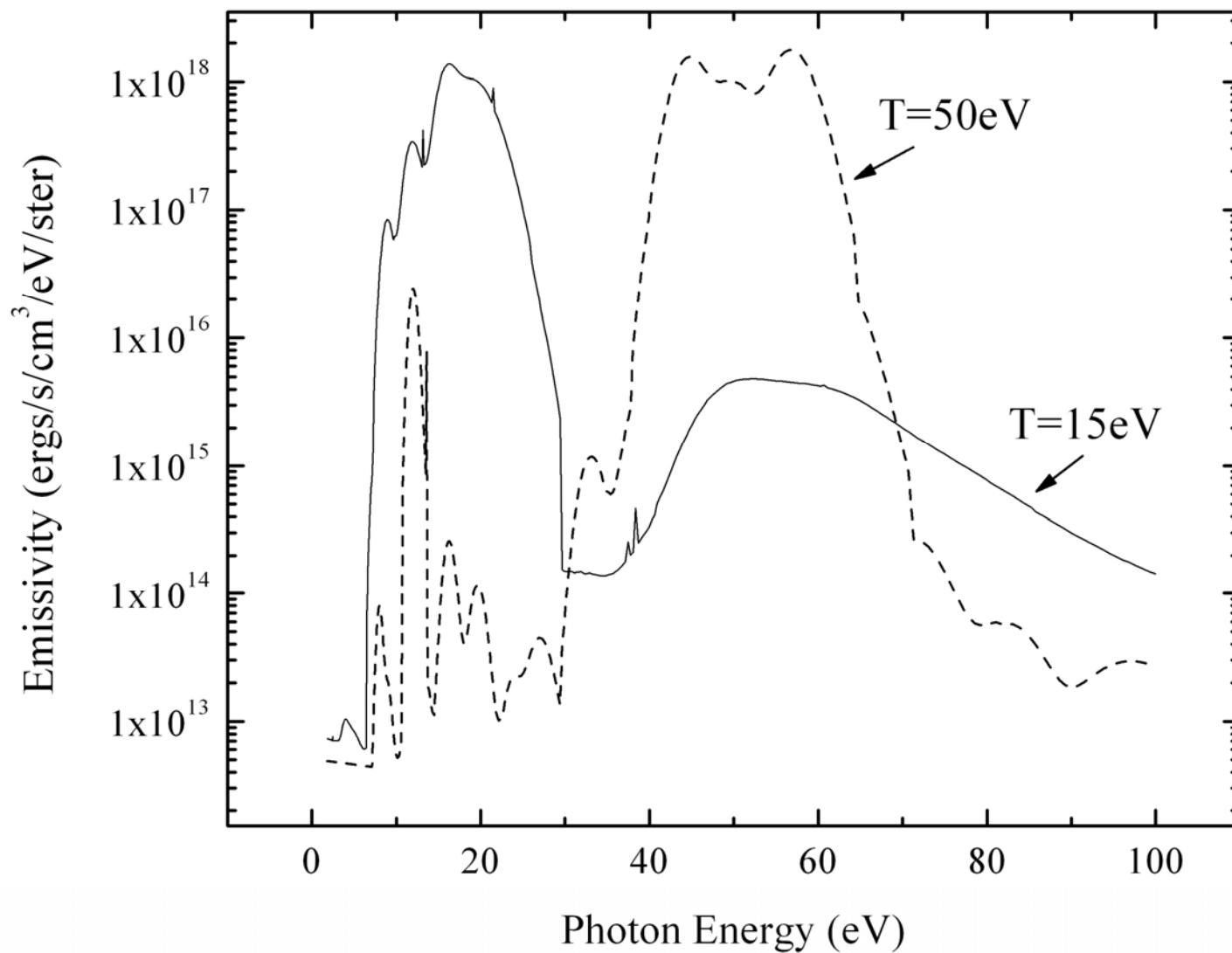
Spectrum plotted with logarithmic y-axis. Note the even weaker continuum than in the 15 eV spectrum, as well as the damping wings of the strongest lines.



And the 50 eV spectrum degraded to low resolution
(note linear y-axis)



Logarithmic representation of the low-resolution spectrum,
compared to the 15 low-resolution spectrum.



Conclusions

- The spectrum is line dominated (and seems that it would be for significantly lower impurity levels)
- A small number of strong lines dominate
 - In a given spectrum (at a specific temperature) a single element can completely dominate the emission
 - At low resolution, the spectrum is moderately peaked, at $h\nu \sim kT$
 - Over this range – a few 10s of eV – the emissivity is of order 10^{18} ergs/s/cm³/ster/eV

Future Work

- More of the strong lines should be identified in the 50 eV case
- Lower (or different) impurity levels could be explored
- Given a time-history of temperature and density, we could perform a time-dependent calculation – there's a very good chance that the plasma is far from equilibrium